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## Article

# Evidence of abnormal hot carrier thermalization at van Hove singularity of twisted bilayer graphene

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#### **ABSTRACT**

Interlayer twist evokes revolutionary changes to the optical and electronic properties of twisted bilayer graphene (TBG) for electronics, photonics and optoelectronics. Although the ground state responses in TBG have been vastly and clearly studied, the dynamic process of its photoexcited carrier states mainly remains elusive. Here, we unveil the photoexcited hot carrier dynamics in TBG by time-resolved ultrafast photoluminescence (PL) autocorrelation spectroscopy. We demonstrate the unconventional ultrafast PL emission between the van Hove singularities (VHSs) with a  $\sim$ 4 times prolonged relaxation lifetime. This intriguing photoexcited carrier behavior is ascribed to the abnormal hot carrier thermalization brought by bottleneck effects at VHSs and interlayer charge distribution process. Our study on hot carrier dynamics in TBG offers new insights into the excited states and correlated physics of graphene twistronics systems.

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### 1. Introduction

In the past decades, hot carriers in graphene have been exhaustively studied and exploited in various fields. Owing to the unique linear band structure, the carriers in graphene are endowed with very rapid carrier-carrier scattering assisted by strong Coulomb interaction  $[1-3]$ . After excitation, the intraband carrier scattering first impels photoexcited electrons and holes to thermalize independently among the conduction and valence bands with unequal chemical potentials ( $\mu_e \neq \mu_h$ ), which grants graphene the capability of population inversion and stimulated emission  $[4,5]$ . Then the interband carrier scattering process gradually drives hot carriers to reach thermal equilibrium with an electronic temperature of up to  $\sim$ 3000 K, and extends their distribution among the whole energy band at a timescale of  $\sim$ 30 fs [\[5–7\].](#page-5-0) Finally, hot carriers experience further cooling and relaxation via scattering with optical phonons ( $\sim$ 100 fs) and acoustic phonons ( $\sim$ 1 ps) [\[8–10\].](#page-5-0)

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These various relaxation paths of hot carriers lead to diverse ultrafast phenomena in graphene. For example, the recombination of hot electron-hole pairs brings out broadband ultrafast photoluminescence (PL), which has been used as a broadband white light source [\[11,12\].](#page-5-0) The ultrafast and efficient hot carrier harvesting among graphene and various semiconducting materials has been fully studied with potential applications for high-energy conversion [\[13–18\].](#page-5-0) And the hot carrier scattering process can overcome the vacuum barrier due to strong electron–electron interaction and serve as a source of hot electron emission [\[19\].](#page-5-0) These intriguing carrier dynamic behaviors and the diverse ultrafast phenomena make graphene an excellent platform for advanced optoelectronics and photonics [\[20–24\].](#page-5-0)

As a unique engineering method for two-dimensional (2D) materials, interlayer twisting brings new opportunities in both fundamental physics and applications into grapheme [\[25–28\].](#page-5-0) For relatively large angles, twisted bilayer graphene (TBG) manifests novel properties, including the enhanced density of states, intensified light absorption and strongly bound excitons, all emerging at the van Hove singularities (VHSs) induced by inter-layer interaction and band reconstruction [\[29–31\].](#page-6-0) As the twist angle is progressively reduced, the strong correlation of electrons

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leads to further marvelous discoveries in magic-angle TBG, such as the flat bands in the mini-Brillouin zone, correlated insulating states, superconductivity, ferromagnetism, and topological phase transition [\[32–37\]](#page-6-0). With all these fascinating optical and electronic properties, TBG-like 2D material systems have infused new vitality to the research frontiers of materials science and condensed matter physics. However, research until now on TBG is limited to the ground state, and the photoexcited state dynamical properties of TBG, representing one of the irreplaceable aspects of its physical picture and cornerstone for its application design, are still little studied.

The main challenge to probe the hot carrier dynamics in TBG can be attributed to the complexity of the transient absorption spectroscopy towards TBG circumstance (in particular, at the VHS), although it has been widely used in monolayer graphene (MLG)  $[2,4]$ . In MLG, the carrier relaxation lifetime can be inferred by transient absorption dynamics by resolving the intrabandinterband absorption competing mechanism. However, the energy band reconstruction introduces intersubband transition, and the emergence of VHS in the density of states complicate the weight of intra- and inter-band contribution, which all hinder the deciphering of the exact carrier relaxation lifetime in TBG [\[10,38\].](#page-5-0) Moreover, the carrier dynamics of the VHS in TBG is entangled with free carriers of the same energy level on the linear bands, and it is challenging to isolate the VHS contribution in the transient absorption dynamics.

Here, we propose the time-resolved PL autocorrelation method to unveil the ultrafast hot carrier dynamics in TBG. As ultrafast PL intensity is linearly correlated with the transient hot carrier density, time-resolved PL autocorrelation should be a faithful reflection to the carrier dynamics [\[12,39\]](#page-5-0). Meanwhile, by extracting the peak components from PL spectra, which represent the pure VHS contribution, we can successfully recover the VHS carrier dynamics from the carrier mixture. We find that the ultrafast hot carriers on the linear bands of TBG behave similarly to MLG, while the carriers captured by VHS possess decelerated dynamics, which is 4-time longer than that of MLG. Further time-dependent density functional theory (TDDFT) suggests that the prolonged lifetime is attributed to the abnormal hot carrier thermalization brought by bottleneck effect at mini-gaps and interlayer charge redistribution process in real space. Moreover, such thermalization process is asymmetric between electrons and holes, which have different relaxation lifetimes.

### 2. Materials and methods

#### 2.1. Sample fabrication

The MLG is obtained by mechanical exfoliation from HOPG bulk crystals onto a 90 nm  $SiO<sub>2</sub>/Si$  substrate. Then we carry out the drytransfer process on our home-built 2D material transfer stage. Using a PPC membrane/PDMS structure as a stamp, we first pick up  $\sim$ 20 nm thick h-BN flake, and then pick up half of the MLG sample with the h-BN flake. After fine rotation of the remaining graphene sample by rotational stage, we finally release the h-BN/ graphene from the stamp onto the remaining graphene. The whole h-BN/TBG sample is then annealed in  $Ar/H<sub>2</sub>$  atmosphere at 400 °C for 8 h to remove the residual PPC.

### 2.2. Spectroscopy measurement

For PL spectra measurement, Ti:sapphire oscillator (Coherent Vitara laser) with femtosecond pulses ( $\sim$ 25 fs, 80 MHz, 820 nm) is used to excite the ultrafast PL of TBG. The pump laser is focused onto the sample by a Cassegrain objective to avoid possible chirpinduced pulse stretching. The PL signal is collected by the same objective and detected by a spectrometer (Princeton Acton SP2500). A 750 nm short-pass filter is used to eliminate the pump signal. For the differential reflectance spectra, a supercontinuum laser source (YSL, 400–2600 nm, 1 MHz, 10 ps) is used as the excitation, and the reflection signal is also collected by a spectrometer (Princeton Acton SP2500). The reflection signal of the substrate is also collected to calculate the differential reflectance.

### 2.3. Time-resolved ultrafast PL spectroscopy

Ti:sapphire oscillator (Coherent Vitara laser) is used to conduct the ultrafast PL autocorrelation measurement. The output beam is split by an optical 50:50 beamsplitter, and the light path of one beam is controlled by a motorized delay stage to introduce a time delay. Then two beams are focused onto the sample by a Cassegrain objective. A BBO crystal is used to yield traditional interferometric autocorrelation second-harmonic signal, so that we can monitor the final pulse width when they reach the samples. Prism pairs are used as chirp compensation to compress the pulse width until the final width is controlled as shorter than 30 fs. After that, we monitor the PL signals of TBG and record a series of spectra under different time delays. The autocorrelation traces are obtained by integrating the spectral fluences of the certain wavelength range from the spectra of different time delays.

#### 2.4. Calculation

The ground-state properties of TBG are calculated based on DFT using VASP software [\[40,41\]](#page-6-0). We use a Moiré-supercell with an optimized lattice constant of 10.79 Å. The supercell contains two graphene layers twisted at an angle of 13.2°, with an interlayer distance of 3.4 Å. A vacuum space of 20 Å is introduced along the zaxis, perpendicular to the surface. The Brillouin zone is sampled by  $5 \times 5 \times 1$  k-point mesh for calculations. We utilize planewave basis sets with a cut-off energy of 500 eV and employ the norm-conserving pseudopotential to describe the interaction between valence electrons and ions and use the Perdew–Burke–E rnzerhof (PBE) functional with the generalized gradient approximation (GGA) to calculate the exchange–correlation energy [\[42\].](#page-6-0) The total energy converges to within  $10^{-8}$  eV for all calculations.

We perform time-dependent density functional theory molecular dynamics (TDDFT-MD) simulations using the time-dependent ab-initio packages (TDAP) as implemented in the SIESTA software [\[43–45\]](#page-6-0). Due to the use of different software, the interlayer distance slightly decreased to 3.23 Å after relaxation, which satisfies the force convergence criterion of 0.005 eV/Å. The van der Waals interactions between layers are considered using the DFT-D3 method. The basis set consists of numerical atomic orbitals with double zeta polarization (DZP), and the electron-nuclear interaction is described by Troullier-Martins pseudopotentials. We utilize an auxiliary real-space grid equivalent to a plane-wave cutoff of 300 Ry and apply a 4  $\times$  4  $\times$  4 k-mesh to sample the Brillouin zone. In order to simulate the thermalization process of carriers, we analyze the electronic structure of TBG by artificially inverting the population: we remove electrons from the valence band and self-consistently fill them into the conduction band at the M point. Subsequently, the time-dependent Kohn-Sham wavefunctions of TBG evolve in the NVE ensemble at 300 k for up to 800,000 attoseconds (800 fs) with a time step of 50 attoseconds. Throughout the real-time evolutions, the nonadiabatic couplings (i.e., the correlated electron–phonon dynamics beyond the Born-Oppenheimer approximation) are governed by the Ehrenfest theorem.

#### 3. Results and discussion

#### 3.1. Ultrafast PL spectroscopy

In our experiments, TBG samples with different twist angles are prepared by dry-transfer method onto a 90 nm  $SiO<sub>2</sub>/Si$  substrate ([Fig. 1](#page-3-0)a, b). Under pulsed laser excitation, photoexcited hot carriers in graphene will be scattered to high energy and generate a broadband ultrafast PL ([Fig. 1](#page-3-0)c). The representative ultrafast PL spectra of MLG and TBG (with a twist angle of  $\sim 11^{\circ}$ ) under the same exper-imental conditions are shown in [Fig. 1d](#page-3-0). Compared to the monotonous curve of MLG, TBG shows a clear peak. For a more intuitive view, we extract the peak signal from the broad ultrafast PL background by subtracting a baseline spectrum inspired by that of the MLG [\(Fig. 1](#page-3-0)e). This PL peak's position evolves correspondingly with the twist angles [\(Fig. 1](#page-3-0)f), indicating that it is highly correlated with VHS. These results agree well with previous reports which used photoluminescence excitation spectra [\[46\],](#page-6-0) meanwhile they are different to photoluminescence excitation spectra because the latter only reflects the absorptivity and contains no signature of the excited carriers. We note that, such peak only exists for upconversion with low photon energy pump and vanishes as excited by high photon energy pulses (with energy larger than the peak, Fig. S1 online). [Fig. 1e](#page-3-0) shows the comparison of differential reflectance spectrum and ultrafast PL spectrum for a  $11^{\circ}$  TBG sample. The extracted PL peak position is located at  $\sim$ 2.03 eV, in sharp contrast to a much higher reflectance peak at  $\sim$ 2.10 eV. Such obvious deviation can be observed for TBG samples with different twist angles (Fig. S2 online). Generally, in the thermal radiation model assuming a unified electron temperature, the emission of ultrafast PL can be described according to the generalized Kirchhoff's Law [\[47\]](#page-6-0), where the emissivity will be proportional to absorptivity. However, it is difficult to reproduce a well-fitted PL spectrum by the absorption spectra, even considering the Fano resonance and the substrate-induced multireflection effects, due to the large deviation between reflectance and PL peaks [\[48\]](#page-6-0).

To determine the origin of the ultrafast PL peaks in TBG, we carry out the excitation power and photon energy-dependent PL measurements. [Fig. 2](#page-3-0)a shows the 2D plot of the extracted PL peak spectra under different excitation powers. The peak position remains unchanged over a wide excitation power range (Fig. S3 online). The integrated total PL fluence and extracted peak fluence exhibit  $\sim l^{1.8}$  power-dependence, similar to that of MLG [\(Fig. 2b](#page-3-0)). The observed nonlinear dependency in the up-conversion PL can be principally ascribed to the carrier-carrier scattering processes after excitation. It necessitates the absorption of photons in excess of a singular equivalent number to facilitate the generation of electron-hole pairs at the elevated energy state. As the density of photoexcited carriers follows a linear dependence on the excitation power within the first  $\sim$ 30 fs [\[1\]](#page-5-0), we believe that the nonlinear PL process involving carrier multiplication and Auger process occurs after the complex carrier scattering processes, which can strongly alter the luminescence behavior of the thermally equilibrated carriers to the nonlinearity regime  $[3,9]$ . The excitation photon energy-dependent PL spectra are carried out by tuning the excitation photon energy from 1.14 to 1.68 eV, with the excitation flu-ence kept the same at 0.59 mJ cm<sup>-2</sup> ([Fig. 2](#page-3-0)c). The spectra remain the same line shape, and the peak fluences show no obvious differences ([Fig. 2](#page-3-0)d). This indicates that the population of hot carriers scattered to the PL peak emission states is almost independent of the excitation photon energy. Similar results also appear in cryogenic experiments at 7 K (Fig. S4 online). Therefore, we can safely conclude that the hot carrier recombination around VHS of TBG mostly occurs at least 30 fs after excitation, when the free carriers have reached thermal equilibrium among the entire Dirac cone.

#### 3.2. Time-resolved PL autocorrelation

The post-thermal-equilibrium feature allows us to analyze the detailed hot carrier dynamics of TBG at VHSs by time-resolved ultrafast PL autocorrelation spectroscopy with a resolution of  $\sim$ 25 fs. As illustrated in [Fig. 3](#page-4-0)a, two laser beams with a time delay are focused on the samples and the ultrafast PL signals are recorded by a spectrometer equipped with a charge-coupled device (See Supplementary materials for details). The timeresolved PL spectra of TBG and MLG show highly time-delay dependent feature, where the PL intensity decreases correspondingly with time-delay  $t$  [\(Fig. 3b](#page-4-0)). For an obvious view, with different integration choices, we can obtain autocorrelation traces regarding to carriers of different energies and momentums. We integrate the PL intensity of TBG and MLG under two different spectral ranges  $(I_1 \ (490-550 \ nm)$  refers to the range away from VHSs, and  $I_2$  (580–630 nm) for the range resonant to VHSs, as shown in [Fig. 3b](#page-4-0)) and draw their traces versus time-delay ([Fig. 3](#page-4-0)c, d). As the integrated PL intensity of graphene is approximately proportional to the peak value of  $n(E)$ , which denotes the density of electrons (holes) at state  $E$  above (below) the Dirac point, the time-resolved PL fluence can be treated as a linear mapping to the dynamical carrier density  $n(t, E)$  at time t after the pulsed laser excitation. Therefore, the carrier lifetime can be directly deciphered by exponential fitting to the PL fluence autocorrelation traces. For the range  $I_1$ , TBG and MLG both show an identical lifetime of  $\sim$ 150 fs ([Fig. 3c](#page-4-0)). For the range  $I_2$ , we find a longer lifetime for TBG as  $\tau_{\text{TBG}}^1 = \sim 190$  fs, and  $\tau_{\text{MLG}}^1 = \sim 150$  fs for MLG [\(Fig. 3](#page-4-0)d). In TBG, this lifetime is contributed by two parts, free carriers on the linear band and carriers linked to VHSs. To separate these two parts and determine the pure carrier lifetime at VHSs, we extract the PL peak intensity at the VHS (as method in [Fig. 1](#page-3-0)e) and plot its autocorrelation trace. The pure carrier lifetime at VHSs is determined to be  $\tau_{VHS} = \sim 600$  fs ([Fig. 3e](#page-4-0)), much longer than the carrier-optical phonon scattering at the linear bands of both TBG and MLG. Moreover,  $\tau_{VHS}$  is almost independent of the excitation power, in contrast to that of  $\tau_{MLG}$  which decreases with the incident power in our experiments (Fig. S5 online). This anomalous behavior also indicates the abnormal carrier dynamic process at the VHSs.

#### 3.3. TDDFT calculation

In the following, we conduct the TDDFT simulations to comprehend the complex carrier evolution in TBG. TBG with a  $13.2^\circ$  interlayer twist angle is chosen as it is the commensurate Moiré superlattice close to our experimental samples. First, we calculate the exact band structure of TBG superlattices in the folded Brillouin Zone, which is conducted in a single super-cell containing 76 carbon atoms (Fig. S6a online). Providing the symmetric valence and conduction bands around the Dirac point, the symmetryallowed transition  $X_{13}$  and  $X_{24}$  will degenerate  $(X_{13} = E_3 - E_1,$  $X_{24} = E_4 - E_2$ , [Fig. 1c](#page-3-0)) [\[49\].](#page-6-0) However, the conduction and valence band of graphene is in fact not symmetric, especially when the momentum approaches the M point of Brillouin Zone, due to the differences in electron-electron many-body interaction in the occupied and empty states. Such asymmetry leads to non-degenerate transition energy of  $X_{13}$  and  $X_{24}$  in TBG in our calculation, where  $X_{13}$  holds a lower transition energy and stronger oscillation strength.

Then, we simulate the dynamics at the VHS states using TDDFT method. As illustrated in [Fig. 4](#page-4-0)a, the hot carriers excited by the photon energy below the VHS transition experience an ultrafast thermalization process among the linear-dispersion bands. For MLG, <span id="page-3-0"></span>N. Shang et al. Shang et al. Science Bulletin xxx (xxxx) xxx



Fig. 1. The VHS dominating ultrafast PL of TBG. (a) Schematic representation of TBG under pulse laser excitation. (b) Optical image of the 11° TBG heterostructure, with BN encapsulated on the top. (c) Schematic of TBG's up-converted PL generated at VHS formed by two intersecting Dirac cones in reciprocal space. Only the non-degenerate transitions  $X_{13} = E_3 - E_1$ ,  $X_{24} = E_4 - E_2$  are allowed according to optical selection rules. (d) Ultrafast PL spectra of TBG and MLG excited with a 1.51 eV pulsed laser. An obvious peak appears in the spectrum of TBG. (e) The extracted ultrafast PL peak of 11° TBG and the corresponding differential reflectance spectrum. The PL peak position exhibits a red-shift of ~70 meV compared with the absorption peak. (f) The ultrafast PL peaks of TBG with several representative twist angles (10°, 11°, 12°, 14°). The PL peak position shows a clear dependence on the twist angles.



Fig. 2. The excitation power and photon energy dependent ultrafast PL spectra. (a) The excitation power-dependent extracted PL spectra of TBG. The dash line represents the center of the ultrafast PL peaks. (b) Excitation power dependent ultrafast PL intensity in MBG and TBG. The total ultrafast PL fluence of MLG (wine) and TBG (olive, integrated before peak extraction), and the extracted peaks' fluence (orange, extracted peaks) at VHS increase nonlinearly with the excitation power. A similar nonlinear dependence is observed. (c) The ultrafast PL peak intensity of TBG under different excitation photon energies  $E_{ex}$ . (d) The integrated PL peak fluence, as denoted with the orange area in (c), versus  $E_{\text{ex}}$ . No obvious variation can be observed.

such a process dominated by intraband or interband elastic carrier scattering will drive carriers to reach an equilibrium among the whole bands at the timescale  $\tau_{e-e}$  <30 fs [\[9\]](#page-5-0). For TBG, however, due to the large momentum and energy disparity at VHS, hot carriers in the isolated bands (marked in green in [Fig. 4](#page-4-0)a, b) can hardly be excited by either interband or intraband scattering. It means that the thermalization of TBG is sufficiently blocked by the opening bandgap at VHS. The scattering process between  $E_3(E_2)$  and  $E_4(E_1)$ 

facilitated by phonons becomes the dominating channel for the hot electron (hole) generation in the isolated bands beyond VHS. According to our calculation, the hot holes scattering process from  $E_2$  to  $E_1$  remains ultrafast in a timescale of  $\sim$ 50 fs (Fig. S7 online), while the hot electrons scattering process from  $E_3$  to  $E_4$  is extended to a timescale of  $\tau_{3-4}$  = 650 fs [\(Fig. 4c](#page-4-0), d). The asymmetric dynamical process of electrons and holes may stem from the non-identical coupling strength with phonons [\[50\].](#page-6-0)

<span id="page-4-0"></span>

Fig. 3. The time-resolved PL autocorrelation results. (a) Illustration of the ultrafast PL autocorrelation system. (b) The collected ultrafast PL autocorrelation spectra of TBG under a series of delay times.  $I_1$  and  $I_2$  indicate different integral ranges whose energy is away from VHS  $(I_1)$  or resonant to VHS  $(I_2)$ . (c, d) The ultrafast PL autocorrelation traces of TBG and MLG away from VHS (c), and resonant to VHS (d). Under resonance at VHS, the relaxation lifetime of TBG and MLG is quite different with  $\tau_\text{HcG}^\text{H}$  = $\sim$ 190 fs and  $\tau_{\rm MLG}^1$ = $\sim$ 150 fs. (e) The extracted pure carrier lifetime of TBG at VHS. It gives a lifetime  $\tau_{\rm VHS}$ =  $\sim$ 600 fs,  $\sim$ 4 times longer than free hot carriers in MLG.



Fig. 4. The abnormal long-term thermalization at VHS. (a) Schematics of the photoexcitation and hot carrier thermalization on the linear bands. (b) Schematics of the thermalization between VHS  $E_3$  and  $E_4$  facilitated by phonon scattering. (c) TDDFT calculated electron occupation evolution of  $E_3$  (top panel) and  $E_4$  (bottom panel). The lifetime when occupation drops to 1/e is about 650 fs, indicating an abnormal long-term thermalization lifetime. (d) The calculated charge density distribution in real space for a TBG supercell. The top panel illustrates the real-space distribution of  $E_3$ , and the bottom panel illustrates  $E_4$ . The interlayer charge density distribution exhibits a noticeable difference. (e) The averaged charge density along the z-axis (out of plan) in TBG. The differential charge density distribution  $\Delta_{34}$  (the difference between  $E_4$  and  $E_3$ ) reveals a clear interlayer charge redistribution process.

The electron blocking at  $E_3$ , together with the lower transition energy and stronger oscillation strength of  $X_{13}$ , make it directly dominate the PL emission with prolonged lifetime at VHS. Furthermore, as the carrier lifetime of VHS is different from that of the linear bands, there will be no signature of Fano resonance in the PL

spectra as we experimentally measured. Considering the absorption spectra are contributed by both  $X_{13}$  and  $X_{24}$ , with substantial Fano resonance to the continuum spectra, meanwhile the PL spectra are solely contributed by  $X_{13}$ , we believe this is the reason for the red-shifted PL peaks compared to the absorption. Moreover,

<span id="page-5-0"></span>this also responds for the increased energy splitting between peaks of PL and absorption with twist angle increases, as shown in Fig. S2 (online). We note that, the phonon bottleneck effect also exists under higher pump photon energy excitation, where the electrons will accumulate at  $E_4$ . Meanwhile, the oscillation strength of  $X_{24}$  is markedly weak, resulting an undetectable signal in our experiments.

To further elucidate the origin of the prolonged thermalization  $\tau_{3-4}$ , we calculate the real-space localized charge density of  $E_3$  and  $E_4$ , as illustrated in [Fig. 4](#page-4-0)d. Compared to  $E_4$ , the carrier density of  $E_3$ is more delocalized with many carriers distributed between two graphene layers. For a clearer perspective, we calculate the average charge density along the z-axis in the real space for  $E_4$  and  $E_3$ , and plot their difference denoted as  $\Delta_{34}$  ([Fig. 4](#page-4-0)e). The difference curve  $\Delta_{34}$  directly reflects the gain (positive) and loss (negative) of charge during thermalization in real space. A noticeable charge density redistribution can be spotted, where carriers diffuse from interlayer space onto the graphene layers. We conclude that this charge redistribution process and the bottleneck effect emerging at the VHS mini gaps should be the main reasons for the abnormal long-term thermalization process observed in our ultrafast PL autocorrelation spectroscopy.

#### 4. Conclusion

In summary, we have investigated the ultrafast excited state dynamics in TBG under the influence of interlayer couplings. Using time-resolved ultrafast PL autocorrelation spectroscopy, we have detected an abnormal long-term thermalization process triggered by interlayer interaction at the VHS mini-bands. Our exploration should have important implications for the design of TBG-based ultrafast photonics and optoelectronics devices, such as lightharvesting, light-sensing or light-emitting devices. Meanwhile, our technique should be a unique spectroscopy method to investigate the fundamental element interaction in TBG at small twist angles, when the system lies in a strong-correlation regime at a cryogenic environment. We expect that the abnormal dynamics at VHS will bring more intriguing physics to TBG and its family.

#### Conflict of interest

The authors declare that they have no conflict of interest.

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#### Author contributions

Hao Hong, Kaihui Liu, and Sheng Meng conceived and supervised the projects. Nianze Shang performed the device fabrication. Nianze Shang and Chen Huang performed the ultrafast spectroscopy and time-resolved PL autocorrelation experiments. Qing Chen contributed the theoretical calculations. Guangjie Yao, Chang Liu, and Zhipei Sun suggested the optical experiments. All the authors discussed and contributed to writing the paper.

#### Appendix A. Supplementary materials

Supplementary materials to this article can be found online at [https://doi.org/10.1016/j.scib.2024.06.019.](https://doi.org/10.1016/j.scib.2024.06.019)

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